

#### **Features**

- UL recognition, file #E313149
- Ideal for automated placement
- Glass passivated chip junction
- High surge current capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

#### **Typical Applications**

General purpose use in AC/DC bridge full wave rectification for power supply, lighting ballast, battery charger, home appliances, office equipment, and telecommunication applications.

#### **Mechanical Data**

• Package: MBLS

Molding compound meets UL 94 V-0 flammability

• Terminals: Tin plated leads, solderable per

J-STD-002 and JESD22-B102

• Polarity: As marked on body

#### ■Maximum Ratings (T<sub>a</sub>=25°C Unless otherwise specified)

- Maximum Natings (12-20 © Offices otherwise specified)								
PARAMETER	SYMBOL	UNIT	HDL1S	HDL2S	HDL4S	HDL6S	HDL8S	HDL10S
Device marking code			HDL1S	HDL2S	HDL4S	HDL6S	HDL8S	HDL10S
Maximum Repetitive Peak Reverse Voltage	VRRM	٧	100	200	400	600	800	1000
Maximum RMS Voltage	VRMS	V	70	140	280	420	560	700
Maximum DC blocking Voltage	VDC	V	100	200	400	600	800	1000
Average rectified output current @60Hz sine wave, R-load, Tc=125℃	Ю	Α	0.8					
Forward Surge Current (Non-repetitive) @8.3ms Half-sine wave,1 cycle, Tj=25°C	IFSM	Α	25					
Current squared time @1ms≤t<8.3ms Tj=25℃,Rating of per diode	l²t	A <sup>2</sup> s	2.6					
Storage temperature	T <sub>stg</sub>	°C	-55 ~ <b>+</b> 150					
Junction temperature	Tj	°C	-55 ~ +150					

### **■Electrical Characteristics** (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	HDL1S	HDL2S	HDL4S	HDL6S	HDL8S	HDL10S
Maximum instantaneous forward voltage drop per diode	VF	٧	IFM=0.4A	1.0					
Maximum DC reverse current at	: IR		T <sub>j</sub> =25°C	5					
rated DC blocking voltage per diode	ıĸ .	μA	T <sub>j</sub> =125℃	50					
Typical junction capacitance	Cj		Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C			(	6		



#### ■Thermal Characteristics (Ta=25°C Unless otherwise specified)

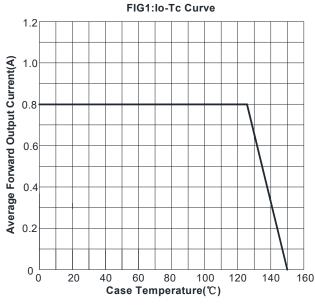
F	PARAMETER	SYMBOL	UNIT	HDL1S	HDL2S	HDL4S	HDL6S	HDL8S	HDL10S	
T i l	Between junction and ambient	R <sub>0</sub> J-A		65.0						
Typical Thermal Resistance	Between junction and lead	R <sub>0</sub> J-L	°C/W			28	3.0			
ivesistatice	Between junction and case	RøJ-C		18.0						

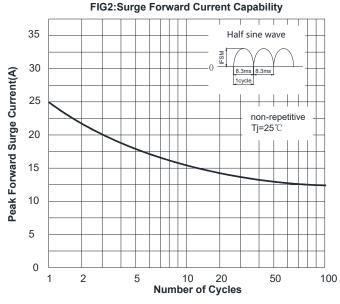
Note: Device mounted on P.C.B with 35mm\*25mm\*1.7mm.

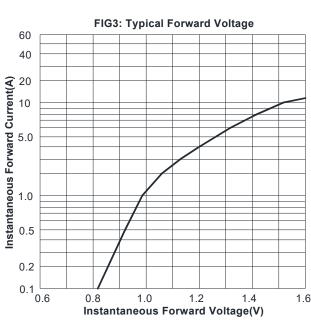
**■Ordering Information** (Example)

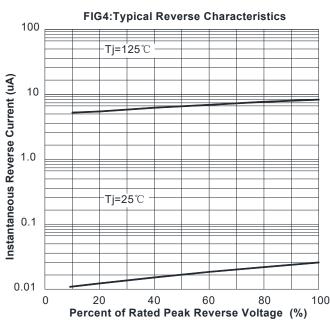
PREFERED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
HDL1S ~ HDL10S	F1	Approximate 0.083	4000	1	64000	13' reel
HDL1S ~ HDL10S	F3	Approximate 0.083	5000	1	80000	13' reel

#### **■ Characteristics** (Typical)



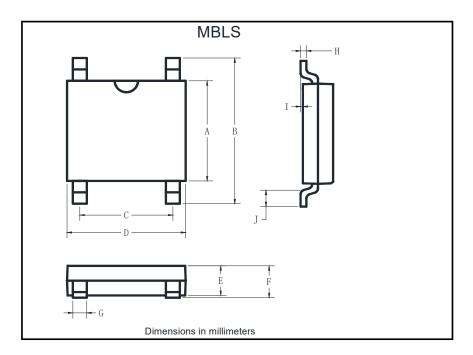






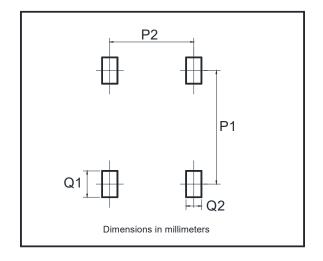


#### **■ Outline Dimensions**



MBLS					
Dim	Min	Max			
Α	3.60	4.00			
В	6.40	7.00			
С	2.20	2.60			
D	4.50	4.90			
Е	1.30	1.50			
F	1.40	1.60			
G	0.56	0.84			
Н	0.15	0.35			
I	0.20Max				
J	0.70	1.10			

# ■ Suggested pad layout



Dim	Min
P1	6.00
P2	2.40
Q1	1.84
Q2	1.20



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